



# RealSSD™ Embedded USB Mass Storage Drive

MTFDCAE001SAF, MTFDCAE002SAF,  
MTFDCAE004SAF, MTFDCAE008SAF

## Features

- Micron® NAND Flash
- Interface: Universal Serial Bus (USB) Specification, Revision 2.0
- USB support
  - USB Specification, Revisions 2.0, 1.1
  - USB Mass Storage Class Specification, Revision 1.0
- Performance
  - Sequential READ: 33 MB/s<sup>1</sup>
  - Sequential WRITE: 22 MB/s<sup>1</sup>
- Reliability: 4 million operating hours mean time between failures (MTBF)
- Endurance: useful operating life of at least 5 years under the following conditions:
  - 8,760 power-on hours per year
  - Active 100 percent of power-on hours
  - Typical operating conditions:<sup>3</sup>
    - 1GB module—8 GB/day
    - 2GB module—16 GB/day
    - 4GB module—32 GB/day
    - 8GB module—64 GB/day
- Static and dynamic wear-leveling
- 8-symbol error correction code (ECC)

## Options

- Capacity (unformatted): 1GB, 2GB, 4GB, or 8GB<sup>4</sup>
- Form factor
  - Standard (36.9mm x 26.6mm x 9.6mm)
- Voltage: 5V ±5 percent
- Operating temperature
  - Commercial (0°C to +70°C)
  - Industrial (–40°C to +85°C)

Notes: 1. Typical transfer rate measured with H2BENCH 3.6.

2. Typical IOPS measured with Iometer 2006.07.27 (4KB transfer size; 67 percent READ/33 percent WRITE; addressing: 50 percent random/50 percent sequential).

3. Assumes that 70 percent of total usable drive capacity contains static files.

4. 1GB = 1 billion bytes; formatted capacity is less.

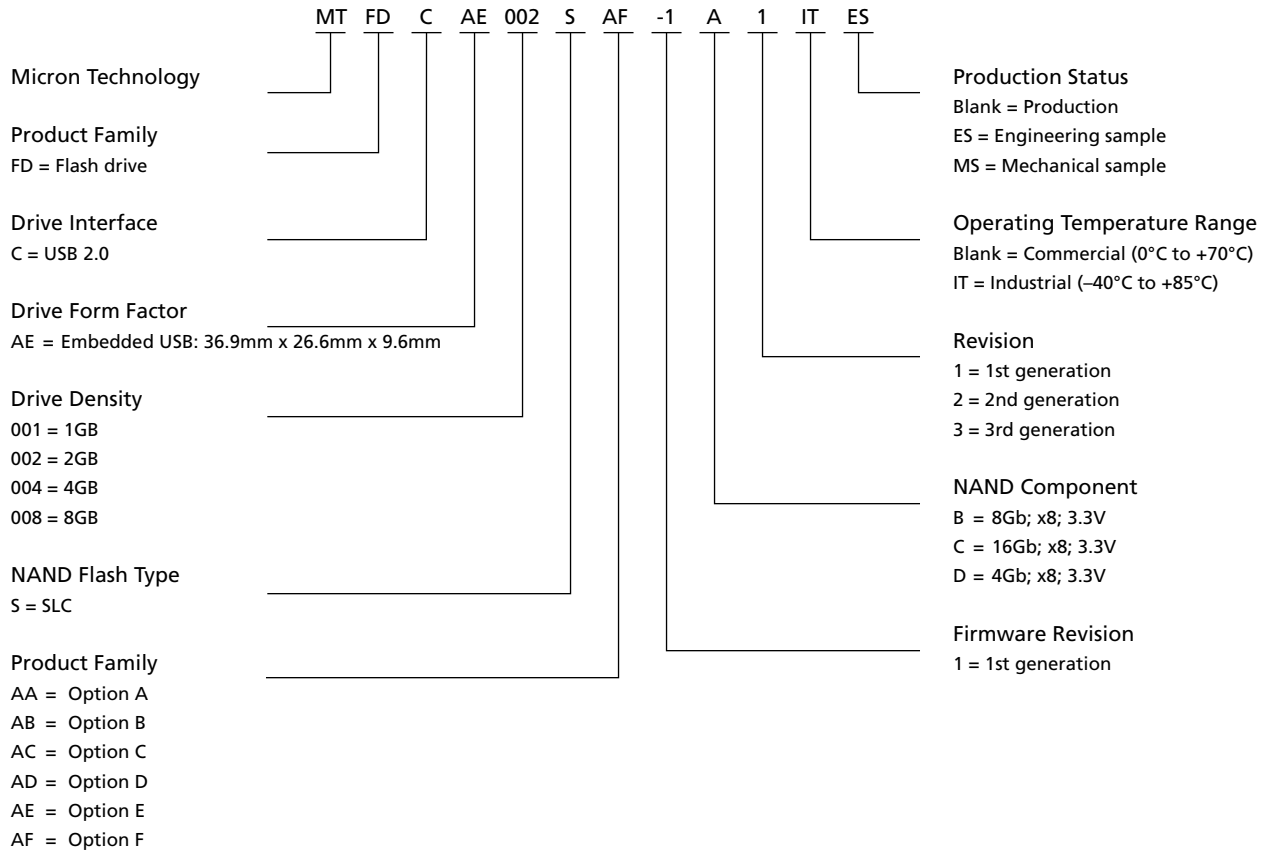


# Embedded USB Mass Storage Drive Part Numbering Information

## Part Numbering Information

Micron RealSSD embedded USB drives are available in several configurations and densities. Visit [micron.com](http://micron.com) for a list of valid part numbers.

Figure 1: Part Number Chart



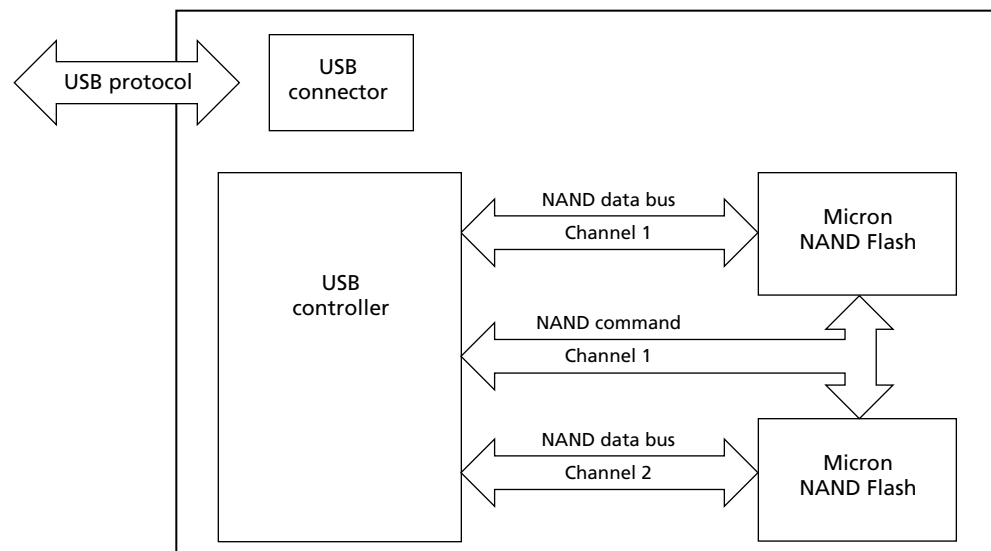
## General Description

Micron's RealSSD™ embedded universal serial bus (USB) mass storage drives provide 1GB, 2GB, 4GB, or 8GB of USB 2.0-compatible memory storage in a small form factor. The embedded USB drive is an ideal solution for applications that require low cost and high reliability. Typical applications include PC caching and boot drives for embedded computing, server, and networking systems.

High performance, reliability, and easy implementation make Micron's RealSSD embedded USBs an ideal storage solution. To consistently deliver the best possible performance, the embedded USB uses only SLC NAND Flash, and all densities use two x8 NAND channels to the controller. In addition to being fast, SLC NAND Flash offers solid reliability, coupled with ECC and wear-leveling. The USB system interface is widely available in many system designs and is easy to implement, enabling rapid time to market.

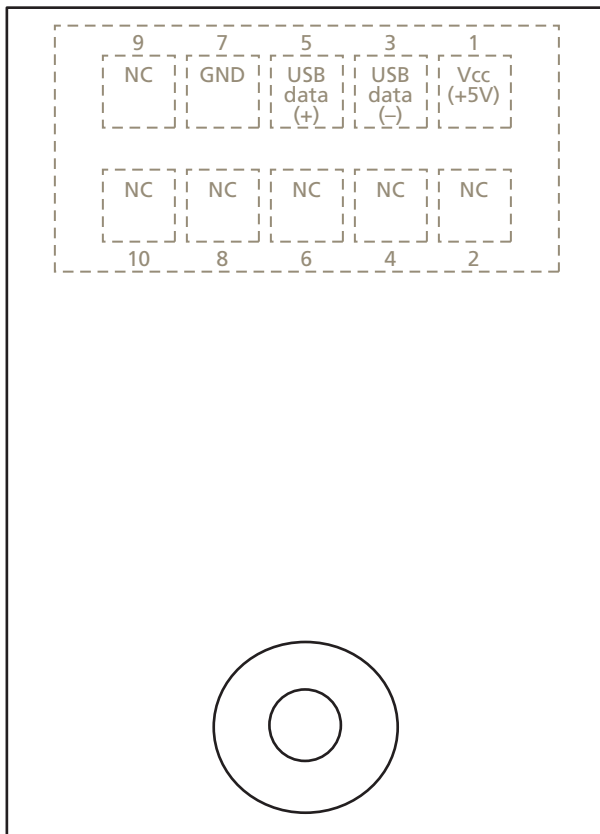
The embedded USB consists of two TSOP-packaged Micron NAND Flash components, a USB controller, and a 10-pin USB connector on a PCB. Different densities are available depending on the number of die in each package and the density of each NAND Flash die (see Figure 2). The drive operates at 5V ±5 percent. It uses industry-standard 10-pin connectors and supports USB Specification, Revision 2.0. It is also backward compatible with Revision 1.1 and can be used with operating systems that support USB Mass Storage Class Specification, Revision 1.0.

**Figure 2: Functional Block Diagram**

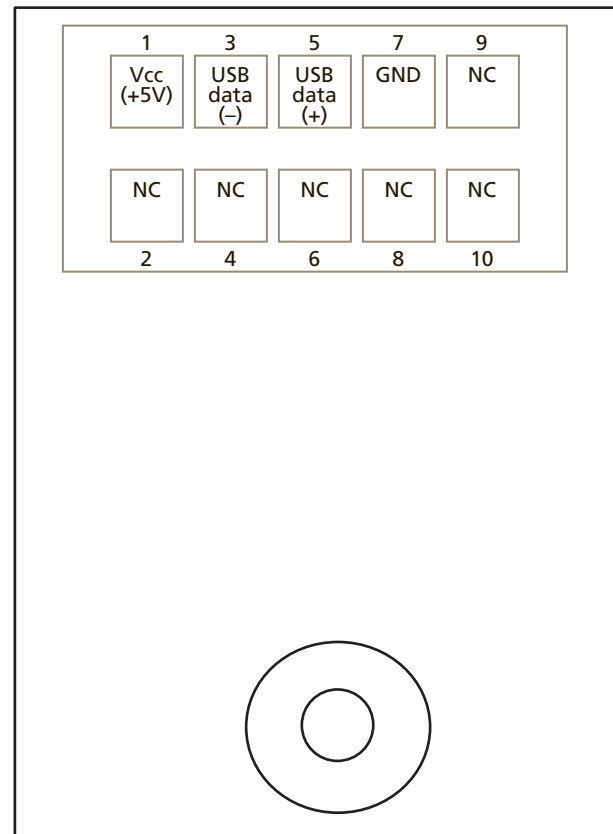


**Table 1: Nominal Dimensions, Density, and Weight**

Dimension	Value	Unit
Height	9.6	mm
Width	26.6	mm
Length	36.9	mm
Density	1, 2, 4, 8	GB
Maximum unit weight	4.5	g

**Figure 3: Pin Assignments: 2 x 5 Connector**


Top view (through PCB)



Bottom view

Notes: 1. Diagram not to scale.

**Table 2: Signal/Pin Descriptions**

Symbol	Type	Function
USB data (+), USB data (-)	I/O	Data inputs/outputs: The bidirectional I/Os transfer address, data, and instruction information. Data is output only during READ operations; at other times the I/Os are inputs.
Vcc	Supply	Vcc power supply pin.
Vss	Supply	Vss ground connection.
NC	-	No connect: NC pins are not internally connected. These pins can be driven or left floating.



## Error Management

The RealSSD embedded USB incorporates advanced technology for defect and error management. It uses various combinations of hardware-based error correction algorithms and firmware-based wear-leveling algorithms.

Over the life of the drive, uncorrectable errors may occur. An uncorrectable error is defined as data that is reported as successfully programmed to the drive, but when it is read out of the drive, the data differs from what was programmed. See Table 4 for the uncorrectable bit error rate.

The mean time between failures (MTBF) can be predicted based on component reliability data obtained by following the methods referenced in the Telecordia SR-332 reliability prediction procedures for electronic equipment.

**Table 3: System Reliability**

Density	MTBF (Operating Hours)
1GB	4.8 million
2GB	4.7 million
4GB	4.4 million
8GB	4.0 million

**Table 4: Uncorrectable Bit Error Rate**

Uncorrectable Bit Error Rate (BER) <sup>1</sup>	Operation
<1 bit error in 10 <sup>15</sup> bits	READ

Notes: 1. BER is measured with a WRITE-to-READ ratio of 1:1.

## Electrical Characteristics

**Table 5: DC and Operating Characteristics**

Parameter	Symbol	Min	Typ	Max	Unit	Condition
Standby current	I <sub>SB</sub>	-	50	TBD	mA	V <sub>CC</sub> = 5V
Active current	I <sub>CC1</sub>	-	100	TBD	mA	V <sub>CC</sub> = 5V

**Table 6: Absolute Maximum Ratings**

Parameter/Condition	Symbol	Min	Max	Unit
V <sub>CC</sub> supply voltage	V <sub>CC</sub>	-0.6	5.25	V

Stresses greater than those listed may cause permanent damage to the drive. This is a stress rating only, and functional operation of the drive at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.


**Table 7: Recommended Operating Conditions**

Parameter/Condition		Symbol	Min	Typ	Max	Unit
Operating temperature	Commercial	TA	0	–	70	°C
	Industrial		–40	–	85	°C
Vcc supply voltage		Vcc	4.75	5.00	5.25	V
Ground supply voltage		Vss	0	0	0	V

**Table 8: Shock and Vibration**

Parameter/Condition	Specification
Operating shock	500 G/2ms
Operating vibration	5–50Hz at 3.1G

## Compliance

Micron RealSSD embedded USB drives comply with the following requirements:

- CE (Europe): EN55022, 1998 and EN55024, 1998
- RoHS, “green” package
- FCC: 47CFR Part 15 Class B
- C-TICK (Australia, New Zealand): approval to AS/NZS CISPR22
- BSMI (Taiwan): approval to CNS 13438
- MIC RRL (South Korea): approval to MIC 2001-115, MIC 2001-116
- CSA (Canada): CSA 22.2 60950
- TUV/GS (Germany): approval to IEC60950/EN6095
- UL (US): approval to UL-60950

## Mechanical Information

The 10-pin (2 x 5) female electrical connector has a height of 7.4mm, a pitch of 2.54 mm, and supports the standard USB 2.0 interface. A mounting hole is also provided on the PCB for a stable, reliable connection to the mounting board.

The motherboard pin headers listed in Table 9 are compatible with Micron’s RealSSD embedded USB drives. Pin headers that are not listed below may also be compatible.

**Table 9: Compatible Pin Headers**

Manufacturer	Part #	Type
Pinrex	212-92-05GB01	SMT
	210-92-05GB01	Straight
Amtek	PHIFS25-205GB	Press fit
	PHIS25-205GB	Straight

## Reference Documents

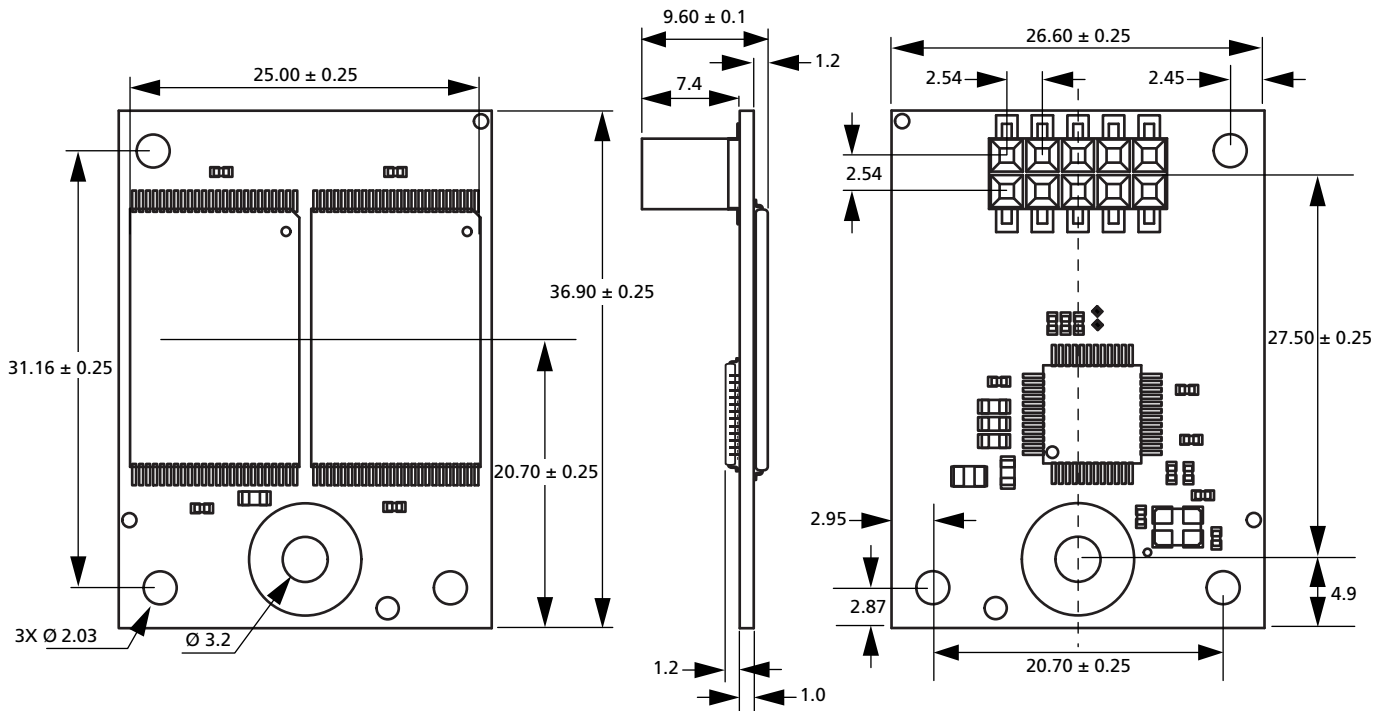
Reference documentation for the USB 2.0 standard (USB 2.0 specification, technical documents, compliance test procedures, and other related documents) can be found at [www.usb.org/developers/docs](http://www.usb.org/developers/docs).



# Embedded USB Mass Storage Drive Package Dimensions

## Package Dimensions

Figure 4: Embedded USB Package



Note: All dimensions are in millimeters.



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 This data sheet contains initial descriptions of products still under development.



## Revision History

Rev. C, Advance .....	5/08
<ul style="list-style-type: none"><li>• Figure 1: Part Number Chart on page 2: Updated NAND component section.</li></ul>	
Rev. B, Advance .....	5/08
<ul style="list-style-type: none"><li>• Updated part numbers.</li><li>• “Features” on page 1: Updated typical operating conditions, performance, endurance.</li><li>• Figure 1: Part Number Chart on page 2: Updated for part number change.</li><li>• “Mechanical Information” on page 6: Added second paragraph and Table 9.</li></ul>	
Rev. A, Advance .....	12/07
<ul style="list-style-type: none"><li>• Initial release</li></ul>	